composition of these compounds. Comparisons were made with similar analyses of the individual oxalates and appropriate physical mixtures thereof. The results indicate that the oxidation state of the iron changes frequently during the course of the decomposition of the complex oxalates and in the region of $700-900^{\circ}$ the principal oxidation state is iron(IV). The components of the mixtures, however, behave independently and do not appear to form significant amounts of iron(IV) at these temperatures. Unfortunately, decomposition of the complex oxalate does not yield stoichiometric barium or strontium ferrate(IV), as had been previously suggested.²

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CONTRIBUTION FROM RCA LABORATORIES, PRINCETON, NEW JERSEY

Rare Earth Sesquiselenides and Sesquitellurides with the Sc2S3 Structure

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The sesquiselenides of Sc, Yb, Tm, Ho, and Y and the sesquitellurides of Tm, Ho, Dy, and Y have the Sc₂S₃ structure which is a superstructure of the NaCl type based on the ordering of cation voids. The tellurides with this structure are stable only over a very narrow range of cation/anion radius ratio, centered at about 0.414. This suggests that the tellurides require both cation-anion and anion-anion contacts to stabilize the structure. The selenides are stable over a wider range of radius ratio, and the relative values of the orthorhombic cell parameters a, b, and c show appreciable deviation from the ideal values 2, $\sqrt{2}$, and $3\sqrt{2}$, respectively, times the NaCl subcell parameter a_0 . Thus, factors other than geometrical considerations are important in determining the stability of the selenides.

Introduction

The rare earth sesquichalcogenides, Ln_2X_3 , of the elements from La to Gd crystallize principally in a defect-type Th₃P₄ structure,¹ of which Ce₂S₃ is a well-known example.² The structures of most of the sesquichalcogenides of the higher atomic number rare earth elements, Tb to Lu, are not well characterized, however. Single crystal data are almost entirely lacking, and even X-ray powder data are not available for many of these compounds of Tb, Ho, and Tm. Although unit cell dimensions for some compounds obtained from X-ray powder data have been reported,^{2–9} only the structures of Yb₂S₃ and Lu₂S₃,⁹ both α -Al₂O₃ type, have been established.

Very recently, however, Haase, Steinfink, and Weiss¹⁰ have shown that Er_2Se_3 and Er_2Te_3 have the Sc_2S_3 -

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type structure,¹¹ which is a superstructure of the NaCl type based on the ordering of cation voids. In Se_2S_3 the unit cell is orthorhombic with $a = 2a_0, b = \sqrt{2}a_0$, and $c = 3\sqrt{2}a_0$, where a_0 is the NaCl-type subcell lattice constant. The axes a, b, and c are parallel to the directions [100], [011], and [011], respectively, of the subcell. The fact that Flahaut, et al.,⁸ have reported a face-centered cubic subcell for many of the sesquiselenides and sesquitellurides of the higher atomic number rare earth elements suggests that the occurrence either of the Sc₂S₃ structure or of another structure having a NaCl-type subcell is widespread in these compounds. The sesquisulfides of these rare earth elements, however, appear not to have the Sc₂S₃ strueture.^{3,4,9,12} Therefore, the present investigation is limited to the occurrence and range of stability of the Sc₂S₃ structure among the sesquiselenides and sesquitellurides of the rare earth elements between Gd and Lu, which also includes Y and Sc because of their chemical similarity.

Experimental

Preparation.—Polycrystalline samples of Se_2Se_3 and Se_2Te_3 were prepared by the direct reaction in stoichiometric propor-

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⁽¹²⁾ We have prepared the sesquisulfides of all the high atomic number rare earth elements. TbyS₃ had the Th;P₄ structure with $a_0 = 8.333$ Å. Ho₂S₃ and Tm₃S₃, data for which have not been published to our knowledge, give very complex powder patterns and appear to be isostructural with Er;S₃ and Y₂S₃. However, indexing of these compounds on the basis of the monoclinic unit cell suggested by Picon, et al.,³ has not yet been tested. The data for Lu₂S₃ agree with that published by Flahaut, et al.⁹ Thus none of these compounds appears to have the Sc₂S₃ structure.

tion of Sc metal with Se or Te vapor in an evacuated quartz ampoule. To prevent the reaction of Sc with quartz, the Sc metal (Fairmont Chemical Co., 97.5% pure) was contained in an aluminum oxide boat, and to prevent oxide contamination from water vapor, both the boat and the ampoule were baked under vacuum at 1000° prior to use. The reaction temperature was set first at the boiling point of Se or Te until most of the reaction was complete, and it was then increased to 1000° for 12 hr. to ensure homogenization. About 0.5 mg./cm.3 of I2 was included to speed up the reaction, and in the case of Sc₂Te₃, some chemical transport13 was observed even with the small temperature gradient in the tube furnace. Subsequently it was established that both Sc2Se3 and Sc2Te3 transport from hot to cold, as was observed previously for Sc₂S₈.¹¹ Single crystals of $\mathrm{Sc}_2\mathrm{Se}_3$ and $\mathrm{Sc}_2\mathrm{Te}_3{}^{14}$ and a polycrystalline alloy of the two compounds with the formula $Sc_2Te_{0.33}Se_{2.67}$ were prepared by the transport technique. The intended alloy composition, based on the ratio of the Sc_2Se_3 and Sc_2Te_3 starting mixture, was Sc_2 -TeSe2. The lower tellurium content of the transported alloy might be due to much faster Se transport than Te transport in this experiment. It is also possible that compositions richer in Te than $Sc_2Te_{0.83}Se_{2.67}$ are not stable. However, no further experiments have been performed to clarify this point. Data on the transport experiments are summarized in Table I. Chemical analyses on a 75-mg. sample established the Te/Se ratio in the Sc₂Se₃-Sc₂Te₃ alloy. Anal. Calcd. for Sc₂Te_{0.38}Se_{2.67}: Sc, 26.2; Se, 61.5; Te, 12.3. Found: Sc, 25.8, Se, 60.0: Te, 12.0.

TABLE I

TYPICAL CONDITIONS FOR CHEMICAL TRANSPORT OF SCANDIUM CHALCOGENIDES WITH I.

Material transported ^a	Transport rate, µmoles hr. ⁻¹	I ₂ concn., ^b mg./cm. ^s	Temp., °C.								
Sc ₂ S ₃	46	1.6	1090 - 920								
Sc ₂ Se ₃	10	1,15	1050 - 950								
Sc ₂ Te ₃	7.9	1.15	1050 - 950								
Sc2Te0.33Se2.67	6.3	0.86	1000-950								

 a Ampoules 2.0 cm, i.d. \times 25 cm. long were used. $~^\circ$ 1 mg./ cm. $^\circ$ of I_2 $~\approx 0.4$ atm.

Polycrystalline samples of the sesquiselenides and sesquitellurides of the rare earth elements from Gd to Yb and of Y were prepared under conditions very similar to those employed in preparing Sc_2Sc_3 and Sc_2Tc_3 . However, I_2 was not used to speed up the reaction. In most experiments rare earth metal in filing form (American Potash and Chemical Corp., 99.9% pure) was used. But, since the question of oxide contamination is important in chalcogenides, for comparison a few samples were also prepared from bulk metal polished to a bright finish. Since the same chalcogenide prepared by the two methods gave identical X-ray powder patterns, the structures found do not appear due to spurious stabilization by oxygen contamination. The reactions appeared complete in all cases except for that of ytterbium with tellurium, where the reaction proceeded only to YbTe.

X-Ray Measurements.—All X-ray data were taken with Nifiltered Cu K α radiation. For Sc₂Se₃ several reciprocal lattice layers were recorded from a small crystal ($\sim 0.1 \text{ mm.}$) using the equi-inclination Weissenberg technique. The crystals were found to be orthorhombic and the space group to be Fddd. The reflection intensities were compared directly with those of Sc₂S₃, and it was established that Sc₂Se₃ and Sc₂S₈ are isostructural. For the superlattice reflections the intensity ratios corresponded very closely in the two compounds, but in Sc₂Se₃ these reflections were relatively weaker as compared to the subcell reflections. Men'kov, *et al.*,¹⁶ have also prepared Se₂Se₃ and have published powder X-ray data for the compound. The reflections they report are in good agreement with the strong subcell reflections in our patterns, and their data would be consistent with a NaCltype structure with disordered voids. However, since their preparative conditions were very similar to ours, it may be that their patterns were too weak to observe the superlattice reflections.

Single crystal and powder X-ray data showed that Sc₂Te₃ does not have the Sc₂S₈ structure.¹⁴ Powder patterns of Dy₂Se₈ and Tb₂Se₃ prepared in this work could be indexed with orthorhombic cell parameters similar to those of Sb₂S₃.^{16,17} The X-ray patterns of Tb2Te3 and Gd2Te3 were complex and did not resemble any of the rare earth chalcogenide phases for which patterns have been indexed.¹⁸ The powder patterns of the sesquiselenides of Ho, Y, Tm, Yb, and Sc and of the sesquitellurides of Dy, Ho, Y, and Tm are shown in Table II. However, for each pattern many high index lines are not listed due to the complexity of the patterns. The patterns of these compounds and of the Sc₂Te_{0,33}Se_{2,67} alloy are all characteristic of the Sc₂S₃ structure, which has the following diffraction features: (a) a strong set of lines from the NaCltype subcell, (b) a set of odd index superlattice reflections for which l is never a multiple of 3, and (c) a weaker set of even index superlattice reflections with h + k + l = 4n. These restrictions, in addition to the space group extinctions, arise from the fact that the cation positions are at rational fractions of the cell edges. The Yb₂Se₃ pattern lists all the odd index superlattice lines which could occur within this range except for three which are overlapped by strong subcell lines. The ratio of the intensities of the superlattice lines to those of the strong (even index) subcell lines in different compounds is proportional to the ratio of the square of the cation scattering power to the square of the scattering power of the whole unit cell. Therefore in Sc₂Se₃ and Y₂Te₃ the superlattice lines were relatively the weakest.

For the sesquitellurides in Table II no splitting or pronounced broadening of the back-reflection lines could be detected and the orthorhombic cell dimensions a, b, and c were taken as exactly 2, $\sqrt{2}$, and $3\sqrt{2}$, respectively, times the subcell lattice parameter a_0 . The orthorhombic indices, hkl, may be converted to the subcell indices, HKL, by the formula $[h^2/4 + k^2/2 + l^2/18] =$ $[H^2 + K^2 + L^2]$.

The selenide patterns, however, showed pronounced splitting of the back-reflection lines indicative of deviations of the lattice constants from the ideal ratios. The ratios of the lattice constants could thus be determined with high precision from the back-reflection region. The cell dimensions are given in Table III and are probably accurate to 1 part in 3000.

Discussion

The present results show that the scandium sulfide structure¹¹ occurs widely among the sesquiselenides and the sesquitellurides of the higher atomic number rare earth elements. Thus, with Sc_2S_3 , the nine compounds herein reported, and Er_2Se_3 and Er_2Te_3 recently reported by Haase, *et al.*, ¹⁰ twelve members of this structural type are known. Since scandium and ytterbium sesquiselenides are isostructural, it is also fairly certain that lutetium sesquiselenide has the Sc_2S_3

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⁽¹⁴⁾ Preparation of Sc_2Te_3 is included here since it was used to prepare the $Sc_2Se_3-Sc_2Te_3$ alloy. For its crystal structure see J. G. White and J. P. Dismukes, Abstract G-12 of Annual Meeting, American Crystallographic Association, Bozeman, Mont., July 1964.

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⁽¹⁷⁾ The structural similarity of these compounds to Sb_2S_3 has previously been noted by Flahaut, et al.⁹ However, neither in the present work nor in that of Flahaut has this postulation been substantiated by intensity calculations on the powder data or by single crystal data.

⁽¹⁸⁾ This phase may be identical with that reported, but not indexed, for Gd_2Te_3 by Reid, *et al.*,⁵ and by Flahaut, *et al.*⁶

TABLE II

X-Ray Powder Diffraction Data for Rare Earth Sesquichalcogenides with the SesS3 Structure (Cu K α Radiation)^{*a*}

	¥27*3				Dy2Te	,			Me 2 Te	з			Tr ₂ te	3			¥2 ⁵ °3				110.25c	3			Tr2Se.				15,50				Se for		
hk.	dobs	deale	lobs	hky.	<u>¢obs</u>	<u>desle</u>	1055	E.K.C	<u>40bş</u>	deale	1450	. hkr	dobs	dcalc	lobe	584 B	dabs	deals	Lobs	hk/	dgbs	crale	Lobs	<u>hki</u>	dobs	<u>dealc</u>	1003	<u>hkr</u>	dobs	deals	Libs	<u></u>	Actes	ecale.	Jaz-
311	3.64	3.65	~~~	111	6.84	6.81	۰.	111	6.79	6.78	-	<u> </u>	6.73	6,73	<u>.</u>	111	5.39	6.42	z.'	10	6.34	6.39	τ.	111	6.30	6.33	R	111	6.24	ð.30	-		1.191	to de	~
220	3.51	J.53	¥	212	5.52 4.11	4.10	~	202	5.51	5.50	w.	004	6,39	5.41	~	202	5.06	6.09	ž	202	6.00	5.06	V.4	2 02	5.38	5.12	ŭ.	202	5.93	5.99	2	104	5,20	<u>, 1</u>	12
400]	3.05	3.06		- 11	3.65	3,65	vv	115	4.17	4.16	VN.	220)	3.60	3.44		115	3,91	3.93	÷.	115	3.89	3,9:		115	3.06	3.88	•	115	3.85	3.87		10	4.67	T_{cac}	- 62
3265	3.57			206	3.51	3.53	vv	311	3.64	3.63	24	206	3.47	3,45	•	2201	3.40	3.42	~	022	3.63 3.4D	3.86		022 J11	3.80	3.38	¥	022 311	3.35	3,80	¥¥	7201	5.75	1.23	1.14
- 51	2.34	2.34	AVA.	400	3.05	3,03	V8	220	3.52	3.51	w+	008	3.22	3,21	V¥ B	206	3.31	3.31	•	120	3.22	3.31	ww.e	220]	3,27	3.28	v	220	3.25	3,27	4	200	1.10	1.12	
1,1,11	2.23	2.24	444	131	2.77	2.79	ve	ii/i	1.25	3.26		4001	3,01	3.02	**	0263	3.08	2.85	~~	2063		3.07		117	3.03	3.04	• I	117	3 03	3.03		4.001	2,12	8a -	5.2
04.0				317	2,61	2,61	~~~	0083		3.23	.,	131	2.75	2,16	vv	400)	2.0/	2,86	*4	800	3.05	3.03	~~	008	3.00	3,01	~	800	5,02	3.00		205	2.10	2.19	<
0.0.12	2.10	2.10	•	\$11	2.34	2,34	vv	026	3.04	3.04	¥8	135)	2,57	2.58	Υ.	131	2.63	2,63	VVN	450	2.85	2.85	¥.	400	2.83	2.83	¥4	400	2,82	2.6	¥5	2, 2, 10	5.11	2.6	1.0
620				1,1,11	2.22	2.22	~	131	2.78	2.78		422	2.42	2.42	WW B	404	2.59	2.59	~~~	315	2,80	2.81	ww.	J15 131	2.78	2,79		315	2.77	2.77	~	331	2.07	2.28	
246	1,842	1.843	*	04.01				225	2.38	2.38	~	2,0,10	2.35	2.35	w	135	2.33	2.33		404	2.57	2.58		404	2.56	2.56	÷.,	4.04	2.55	1.55		137)		1.482	
2,2,32/				426	2,16	2.16	*	2,0,10				333	2.31	2.32	×*	422	2.30	2.30	VVW	317	2.43	2.44	v.	117	2.42	2.42	<i></i>	317	2.41	2.42		1,1,11	1.468	1.950	V. v
4,0,12	1.762	1,764	5	620)				511	2.34	2.33	*	1,1,11		2.11		2,0,10	2.24	2,24	*	422	2.29	2,29	~~)	422	2.27	2.27	www.	422	2,26	2.27	Yor .	4.08		1.415	
800	1.528	1.528	¥*	246	1.835	1,842	w	1.1.111	2.23	2.23	~	137	2.20	4.44	W 3	511	2.15	2.21	*	228	2.23	2.24		2.0.10	2.21	2.22	×	2,0,10	2.20	2.10	w.	64.0	1.910	1.418	
260				2,2,12				60		1.14		408		2,10		137	2.10	2.11		3311	2.18	2.20	~	331	2.17	2,18	v	333	2.16	2,17	*	00,12		1.413	
6.2.12	1.402	2.403	VN	4.9.12	1.758	1.764	a,	c0,12	2.15	2.13	•	040		2 13		0405		2.04		137)		2.10		137)		2,03		137	1.04	2.07		317	1,752	260	199
2,0,18				800	1.524	1.528	w.	3,1,11		1 977	-	00,12				426	2.03	2.03	4.9	1,1,11	2.00	2.09	× I	1,1,11	2.0)	2.07	ř I	1,1,11		2.00	*	3,1,117		1.219	
826				066				3371				1 1 11	1,987	1,990	99 9	242	1,896	1.900	VV9	426]	2,02	2,02	V.8	426	2.00	2.00	V8	426	1.995	1.998	VS.	623		1.63-	
4,4,12	1.347	1.307	34	826	1.364	1.367	=	620				517	1,960	1,963	WW	1,1,13	1.806	1,805	-	00,12	1.024	2.02		00,12		2.00		0,12)		L.998		606	11044	1.613	<u> </u>
840				02,18				246	1.835	1.835	۲	531	1.836	1.838	~~~	2,2,12		1,734		242	1.889	. 692		\$15	1.986	1.985	VV¥	515)	1.975	L.977	~~~	440)	1.563	1.345	
465	1.249	1.247		840				2,2,12				620				620	1.751	1.730	~~ .	337)	1 45.5	1,662		244	1.905	1.909	2 1	242	1.897	1.901	2000	4,0,12	1.944	1.552	
4,2,18				8,0,12	2.246	1.246	b	4,0,12	1.738	1.107	2	246	1.817	1,822	w	1,3,11				511		1.857		337		1.845		337]		1.838		64,12]	1.353	1.354	٣
10,1,0				4,2,18/				3,3,11	1.656	1,658	10.4	2,2,12		1 784		048	1.692	1.655	vv B	1,1,13	1.790	1.797	~	3,1,11}	1.840	1.842	*	3,1,11	1,633	1.835	× .	260)		1.245	
10,0,6	1 1 2 7	1.176	~	8,4,12	1,078	1.080	×	5,1,11				4,2,10	1.777	1 771	VVV B	44.0)	1.457	1.663		246		. 733		1,1,13	1,78C	1,781	VV	1,1,13	1.271	1.774	w	6,2,12	1,241	1.243	~
2,6,12				12,001				1,3,13	1.621	1,518	-	048		•••••		4,0,12	1.613	1.557		2,2,12	1,732	1.726	~	246)	1.720	1.725	004	246	1.716	1.719	www.	2.0,18/		1.240	
2,4,18				480				715				4,0,12	1.744	1.744	π.	444		1.604		606		1.721		2,2,12	1.706	1.7:1	- vr (22,12	1,700	1,704	~	826	1.210	1.212	
080	1.080	1,080	÷	8,2,18	1,017	1.018		04,12	1,522	1,522	**	711		1.689		02,12	1.600	1.602	~~~	0485	1.688	1.692	w	606)		1.706		506		1,730		02,18		1.2.2	
00,241				D6,18				260				444	1,686	1.643	9 0 9	3, 3, 11)		1.567		4,2,10	1.580	1,683	v.	1, 3, 11		1.677		1,3,11	1 441	1.670		466.)		1.102	
10,4,6				12,2,6]				6,2,12	1.397	1,356	~~	02,14				5.1,11	1.964	1,563	¥	4.0.12	1.649	1,650	+	42,10	1.009	1.658		4,2,10	1.004	1.500	ve a	8.0,12	1,104	1.105	- 6
10,2,12	1.033	1,033	w	C8,12	.9651	.966	L 9#	2,0,18/				537	1,645	1.446	VVY	628)		1.504		151	1.605	1.607	**	440	1.635	1.641		440	1.630	1.634	n	4,2,187		1.105	
6,4,18				04.24)				826	1.361	1.361		5,1,11				351	1.901	1.499	~~	711	1.593	1.595	v.	151	1.590	1.592	111	151		1.584		2.6,12		1.043	
2,2,24				12,4,0)			4,4,12				1,3,13	1.605	1.607	100	04,12	1.440	1.400		02,14		1.594		211	1.580	1.581		4444	1.580	1,577	W 8	10,2,0	1.042	1.042	e.
480				4,8,12	.9203	.921	0+	84.0				8003				1,1,17	1.402	1.402	vvv	337	1.557	1.560	U	02,14		1.591		02,14		1.575		6.0.18		1.042	
866	1.019	1.019	12	4,4,24				8.0.12	1.244	1,243	2	24,12	1.504	.,510	I	735	:.347	1,348	VVNe	5,1,10		1.557		3,3,11}	1.544	1.546	. 1	3,3,11	1.532	1.546	v	2,4,18/		1,042	
05,18				8,0,24	.8817	.98.	5 ~~	6,2,18				825	1.16	1 251		3,1,17	1.325	1.324	y where	1,3,13	1,520	1.524	ve.	5,1,11		1.544	- 1	5,1,11		1.538		8,4,12	.9569	5571	-
4,0,241				12.4.12		- 14		650				4,4,12	1.570		•	0.0.12		1.291		6241		1.519		1.3.13	1,509	1.510	vw 2	1.3.13	1,502	1.504	~~	286 \		.1564	
08,12	.9561	. 9563		8,6,18	18471	. 54 /	2 N	10,0,6	1.171	1.171	ww.	8401				C2.18	1.285	1.285	,	5,0,10	1,495	. 497	~	715		1,505		1150		1.500		0.5.12		, 9152	
4,6,18				(2,30				6,0,18				466	1.233	1.233	*	1.3.17		1,261		157		493		10,10	1.479	1.485	wa	6,0,10	1.475	1.479	~	10,2,12	.9154	.5150	- 44
12,4,0								2,4,18				4,2,18				1,1,19	1,261		ww	448	1.454	453	VH 8	351		1.478		351		1.472		5,4,18		.9151	
4,8,12	.9218	.9215						8,4,12	1.076	L.076	v	8,4,12	1,069	1.069	0 +	3,2,11	1.243	1.243	7774	04,12	1.433	1.434	2	448	1.437	1,441	W 3	717	1,433	1,434		5.5.247			
4.4.24				1				00,24				00,24												1171		1.440	- 1	4487		1,434		;			

^a vs, very strong; s, strong; m, medium; w, weak; vw, very weak; vvw, very very weak; B, broad.

TABLE III Cell Dimensions for the Tellurides and Selenides with THE SC₂S₃ STRUCTURE

						Subcell
Compound	a, Å.	b, Å.	c, Å.	a/b	c/b	a_0 , Å,
V ₂ Te ₃	12.224	8.642	25.92	1.414	3.000	6.112
Dy_2Te_3	12.220	8.640	25.91	1,414	3.000	6.110
Ho2Te3	12.172	8.605	25.81	1.414	3.000	6.086
Tm_2Te_3	12.084	8.543	25.63	1,414	3.000	6.042
Y_2Se_3	11.455	8.170	24.38	1.402	2.984	5.750
Ho_2Se_3	11.412	8.133	24.27	1.403	2.984	5.726
Tm_2Se_3	11.316	8.056	24.06	1.405	2.987	5.675
Vb ₂ Se ₃	11.274	8.021	23.98	1.406	2.989	5.654
Sc ₂ Se ₃	10.836	7.673	22.95	1.412	2.991	5.418
Sc ₂ Te _{0.33} Se _{2.67}	10.915	7.729	23.12	1.412	2.991	5.458

structure. Since Sc₂Te₃ has a different structure¹⁴ and Yb₂Te₃ could not be obtained in this work, the structures of Lu₂Te₃ and Yb₂Te₃ cannot as yet be characterized.

The cell dimension ratios, a/b and c/b, for the selenides and tellurides with the Sc_2S_3 structure are given in Table III. The deviations in these ratios from their ideal values are measures of the magnitude of distortion in the Sc₂S₃ structure. The tellurides are undistorted, as was discussed above. For the selenides, the magnitude of the distortion increases with increasing cation size from Sc₂Se₃ to Ho₂Se₃. It is probably this distortion which accounts for the change in structure for Dy₂Se₃.

In Table IV the observed cation-anion distances in compounds with the Sc₂S₃ structure are compared with those calculated by summing the cation and anion radii. The radii for the trivalent rare earth ions are those derived from the C-form rare earth oxides by Templeton and Dauben.¹⁹ The radii for trivalent yttrium, 0.894 Å., and for trivalent scandium, 0.731 Å., were obtained by their method from the lattice parame-

TABLE IV CATION-ANION DISTANCES AND RADIUS RATIOS IN THE RARE EARTH SELENIDES AND TELLURIDES

Compound	d_{obsd} , Å.	dealed, Å.	rc /ra
$\mathrm{Sc_2Se_3}^a$	2.709	2.704	0.370
Yb_2Se_3	2.827	2.831	0.435
Tm_2Se_3	2.838	2.842	0.440
Ho_2Se_3	2.863	2.867	0.453
V_2Se_3	2.875	2.867	0.453
Tm_2Te_3	3.021	3.020	0.404
Ho_2Te_3	3.043	3.045	0.416
$\mathrm{Dy}_{2}\mathrm{Te}_{3}$	3.055	3.059	0.422
$\mathrm{Y}_{2}\mathrm{Te}_{3}$	3.056	3.045	0.416
$Sc_2S_3{}^b$	2.590	2.571	0.397

^{*a*} The value 0.731 Å. was taken as the radius of Se^{3+} . ^{*b*} The value 1.84 Å. was taken as the radius of S²⁻.

ters of $Y_2O_3{}^{20}$ and $Sc_2O_3{}^{21}$. The value used for the selenide ion radius, 1.973 Å., and that used for the telluride ion radius, 2.151 Å., are almost identical with the respective radii deduced by Iandelli²² from the rare earth monoselenides and monotellurides with the NaCl structure. There is good agreement between the observed cation-anion distances and the calculated values for the selenides and tellurides, and for Sc₂S₃.

The boundaries of the Sc₂S₃ structure are fairly welldefined, as can be seen with reference to Table V. The selenides with this structure occur between Sc and Ho, and there is a break between Ho and Dy. The tellurides with this structure are stable between Tm and Dy, with breaks in structure between Tm and Sc and between Dy and Tb. The limits of stability may be understood qualitatively in terms of the packing of hard spheres. The cation/anion radius ratio, $r_{\rm c}/r_{\rm a}$, is a convenient parameter for this discussion, and values for the selenides and tellurides with the Sc_2S_3 structure are listed in Table IV. At large r_c/r_a

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⁽¹⁹⁾ D. H. Templeton and C. H. Dauben, J. Am. Chem. Soc., 76, 5237 (1954).

⁽²¹⁾ N.B.S. Circular 539, Vol. III, U. S. Government Printing Office, Washington, D. C., 1954, p. 27.
 (22) A. Iandelli, Z. anorg. allgem. Chem., 288, 81 (1956).

TABLE V												
STABLE STRUCTURES OF THE SESQUICHALCOGENIDES OF THE RARE												
Earth Elements Gd–Lu, Y, and Sc^a												
	Gđ	Тb	Dy	Y	Ho	Er	Tm	Yb	Lu	Sc		
M_2S_3	Α	A	А	D	D	D	D	Е	Е	\mathbf{F}		
M_2Se_3	A B A	В	В	F	F	F	F	F	?F?	F		

 $M_{2}Te_{3} \begin{array}{c} B \\ C \\ C \end{array} C F F F F F F ? ? G \\ C \end{array}$

^a The elements are arranged in order of decreasing cation radius; A, defect $Th_{3}P_{4}$ -type; B, orthorhombic phase; C, unknown; D, monoclinic phase; E, α -Al₂O₈-type; F, Sc₂S₈-type; G, Sc₂Te₃ structure.

the structure probably becomes unstable, because anion-anion contact, which provides a stable framework for a *cation-deficient* structure, no longer occurs. At small $r_{\rm e}/r_{\rm a}$ the structure probably becomes unstable, because the small cation "rattles" in the close packed anion lattice. The individual range of $r_{\rm c}/r_{\rm a}$ for stability of the tellurides (0.404-0.422) with the Sc₂S₃ structure is much narrower than that of the selenides (0.370-0.453). The average value of $r_{\rm c}/r_{\rm a}$, particularly for the tellurides, is also very close to 0.414., the value at which both anion-anion and cation-anion contact occurs.²³ Therefore, it appears that for the tellurides a double framework of these contacts is necessary for the stability of the structure. The selenides with the Sc₂S₃ structure tolerate considerable distortion before the structure becomes unstable. Reasons for this behavior are not immediately obvious, although clearly the hard sphere model can only be an approximation. That Sc_2S_3 is the only sulfide of this structure type is probably a consequence of the large increase in cation

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(23) L. Pauling, "The Nature of the Chemical Bond," Cornell University
Press, Ithaca, N. Y., 3rd Ed., 1960, Chapter 13, pp. 520-530.
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radius between Sc and Lu. The value of r_c/r_a for Sc₂S₃ (0.397) lies within the stability range for the selenides, but that for "Lu₂S₃" (0.461) lies outside it.

A logical extension of the above discussion is to consider whether the nonoccurrence of the Sc₂S₃ structure among other sesquichalcogenides (i.e., other thanthose of the rare earth elements, yttrium, and scandium) can be understood solely in terms of the hard-sphere model. Elements of the first, second, and third transition series will not be considered in order to avoid complications due to crystal field effects. This eliminates from discussion all elements except Al, Ga, In, and Tl. Values of $r_{\rm c}/r_{\rm a}$ for all but two sesquichalcogenides of these elements lie outside the stability limits for the Sc₂S₃ structure. The value of r_c/r_a for In_2S_3 (0.43) falls within the limits established for selenides; but since no limits could be definitely established for sulfides, the prediction may be ambiguous. The value of $r_{\rm c}/r_{\rm a}$ for In₂Se₃ (0.40)²⁴ is definitely within the range for selenides, and the Sc₂S₃ structure would be predicted. However, the best characterized form of this compound occurs in a defect wurtzite structure.²⁶ This is not too surprising, since for $r_{\rm c}/r_{\rm a}$ less than 0.414^{23} structures with tetrahedral coordination in general are more stable than those with octahedral coordination. However, when one recalls that Sc_2Se_3 (0.370) forms the Sc_2S_3 structure, it is apparent that factors other than radius ratio alone are of considerable importance in determining the stability of selenides with this structure.

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Some Phenyltin, -lead, and -antimony Dithiocarbamates

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The preparation and properties of 24 new dithiocarbamates containing phenyl groups bonded to either carbon. tin, lead, or antimony are described. Decomposition of trityl diorganodithiocarbamates gives the corresponding tetraorganothiuram disulfides. Tetraorganothiuram disulfides can be conveniently prepared by the reaction of triphenylantimony dichloride with the appropriate sodium diorganodithiocarbamate. Organometallic sulfides can be conveniently prepared by the reaction of ammonia with a carbon disulfide solution of the appropriate organometallic chloride or oxide.

Although the literature on the dithiocarbamates is quite extensive,¹ to our knowledge only one dithiocarbamate containing phenyl groups bonded to a group IV-B element other than carbon has been reported.² In this paper are reported some dithiocarbamates containing phenyl groups bonded to either carbon, tin, lead, or antimony. The properties and analytical data are summarized in Table I.

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⁽²⁴⁾ The radius of In^{3+} , 0.79 Å, was obtained from the lattice parameter of $In_2O_3^{25}$ using the method of Templeton and Dauben, ¹⁹

⁽²⁵⁾ N.B.S. Circular 539, Vol. V, U. S. Government Printing Office Washington, D. C., 1963, p. 26.

⁽²⁶⁾ S. A. Semiletov, Kristallografiya, 5, 704 (1960).

⁽¹⁾ For a recent review see G. D. Thorn and R. A. Ludwig, "The Dithiocarbamates and Related Compounds," Elsevier Publishing Co., Amsterdam and New York, 1962.